HALOGEN

**FREE** 

# Vishay Siliconix

# P-Channel 20 V (D-S) MOSFET

PRODUCT SUMMARY									
V <sub>DS</sub> (V)	$R_{DS(on)}$ ( $\Omega$ ) (Max.)	I <sub>D</sub> (A) <sup>a</sup>	Q <sub>g</sub> (Typ.)						
-20	0.0145 at V <sub>GS</sub> = -4.5 V	-29.7							
	0.0205 at V <sub>GS</sub> = -2.5 V -25		28 nC						
	0.0330 at V <sub>GS</sub> = -1.8 V	-19.7	20110						
	0.0650 at V <sub>GS</sub> = -1.5 V	-4							



Marking Code: BU **Ordering Information:** 

SiA437DJ-T1-GE3 (Lead (Pb)-free and Halogen-free)

#### **FEATURES**

- TrenchFET® power MOSFET
- Thermally enhanced PowerPAK® SC-70 package RoHS



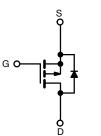
- Low On-Resistance

100 % R<sub>a</sub> tested

· Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

#### **APPLICATIONS**

- Providing low voltage drop in smart phones, tablet PCs, mobile computing:
- Battery switches
- Load switches
- Power management



P-Channel MOSFET

Parameter		Symbol	Limit	Unit
Drain-Source Voltage		V <sub>DS</sub>	-20	.,
Gate-Source Voltage		$V_{GS}$	± 8	V
	T <sub>C</sub> = 25 °C		-29.7	
O-ation - Davis Ones - 150 °O	T <sub>C</sub> = 70 °C		-23.8	
Continuous Drain Current (T <sub>J</sub> = 150 °C)	T <sub>A</sub> = 25 °C	I <sub>D</sub>	-12.6 b, c	
	T <sub>A</sub> = 70 °C		-10 <sup>b, c</sup>	A
Pulsed Drain Current (t = 300 μs)		I <sub>DM</sub>	-60	
Continuous Common Dunis Diodo Commont	T <sub>C</sub> = 25 °C		-16	
Continuous Source-Drain Diode Current	T <sub>A</sub> = 25 °C	I <sub>S</sub>	-2.9 <sup>b, c</sup>	
	T <sub>C</sub> = 25 °C		19	
Maniana Danas Diadia di	T <sub>C</sub> = 70 °C		12	10/
Maximum Power Dissipation	T <sub>A</sub> = 25 °C	P <sub>D</sub>	3.5 <sup>b, c</sup>	W
	T <sub>A</sub> = 70 °C		2.2 b, c	
Operating Junction and Storage Temperature R	ange	T <sub>J</sub> , T <sub>stg</sub>	-50 to 150	***
Soldering Recommendations (Peak Temperatur	e) <sup>d, e</sup>	, and the second	260	- °C

THERMAL RESISTANCE RATINGS									
Parameter	Symbol	Typical	Maximum	Unit					
		$R_{thJA}$	28	36	°C/W				
Maximum Junction-to-Case (Drain)	Steady State	$R_{thJC}$	5.3	6.5	5/44				

#### **Notes**

- a.  $T_C = 25$  °C.
- b. Surface mounted on 1" x 1" FR4 board.
- t = 5 s.
- See solder profile (<a href="https://www.vishay.com/doc?73257">www.vishay.com/doc?73257</a>). The PowerPAK SC-70 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- Rework conditions: Manual soldering with a soldering iron is not recommended for leadless components.
- Maximum under steady state conditions is 80 °C/W.

# Vishay Siliconix

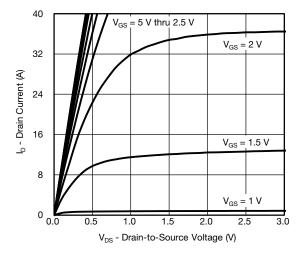
Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit		
Static	Cynnbon	Tool Conditions		. , p.	Waxi	<b>O</b>		
Drain-Source Breakdown Voltage	V <sub>DS</sub>	V <sub>GS</sub> = 0 V, I <sub>D</sub> = -250 μA	-20	_	_	V		
V <sub>DS</sub> Temperature Coefficient	$\Delta V_{DS}/T_{.1}$			-11	_	-		
V <sub>GS(th)</sub> Temperature Coefficient	$\Delta V_{GS(th)}/T_J$	$I_D = -250  \mu A$	_	2.5	_	mV/°C		
Gate-Source Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	-0.4	-	-0.9	V		
Gate-Source Leakage	I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 8 \text{ V}$	-	_	± 100	nA		
	400	$V_{DS} = -20 \text{ V}, V_{GS} = 0 \text{ V}$	-	_	-1	μА		
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> = -20 V, V <sub>GS</sub> = 0 V, T <sub>J</sub> = 55 °C	-	-	-10			
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} \le -5 \text{ V}, V_{GS} = -4.5 \text{ V}$	-10	-	-	Α		
	_(:::)	$V_{GS} = -4.5 \text{ V}, I_D = -8 \text{ A}$	-	0.0120	0.0145	Ω		
		$V_{GS} = -2.5 \text{ V}, I_D = -5 \text{ A}$	-	0.0170	0.0205			
Drain-Source On-State Resistance a	R <sub>DS(on)</sub>	V <sub>GS</sub> = -1.8 V, I <sub>D</sub> = -2 A	-	0.0250	0.0330			
		V <sub>GS</sub> = -1.5 V, I <sub>D</sub> = -2 A	-	0.0370	0.0650	1		
Forward Transconductance a	9 <sub>fs</sub>	$V_{GS} = -10 \text{ V}, I_D = -8 \text{ A}$	-	32	-	S		
Dynamic <sup>b</sup>				•				
Input Capacitance	C <sub>iss</sub>		-	2340	-	pF		
Output Capacitance	C <sub>oss</sub>	$V_{DS} = -10 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$	-	305	-			
Reverse Transfer Capacitance	C <sub>rss</sub>		-	270	-			
Total Oats Observe	0	$V_{DS} = -10 \text{ V}, V_{GS} = -8 \text{ V}, I_D = -13 \text{ A}$	-	60	90	nC		
Total Gate Charge	$Q_g$		-	28	43			
Gate-Source Charge	$Q_{gs}$	$V_{DS} = -10 \text{ V}, V_{GS} = -4.5 \text{ V}, I_{D} = -13 \text{ A}$	-	4.2	-			
Gate-Drain Charge	$Q_{gd}$		-	6.8	-			
Gate Resistance	$R_g$	f = 1 MHz	1.6	8	16	Ω		
Turn-On Delay Time	t <sub>d(on)</sub>		-	20	40	-		
Rise Time	t <sub>r</sub>	$V_{DD}$ = -10 V, $R_L$ = 1 $\Omega$	-	22	45			
Turn-Off Delay Time	t <sub>d(off)</sub>	$I_D \cong$ -10 A, $V_{GEN}$ = -4.5 V, $R_g$ = 1 $\Omega$	-	100	200			
Fall Time	t <sub>f</sub>		-	37	75			
Turn-On Delay Time	Fime t <sub>d(on)</sub>		-	10	20	- ns		
Rise Time	t <sub>r</sub>			10	20			
Turn-Off Delay Time	t <sub>d(off)</sub>	$I_D\cong$ -10 A, $V_{GEN}=$ -8 V, $R_g=$ 1 $\Omega$	-	120	240			
Fall Time	t <sub>f</sub>		-	34	70			
<b>Drain-Source Body Diode Characterist</b>	ics							
Continuous Source-Drain Diode Current	I <sub>S</sub>	T <sub>C</sub> = 25 °C	-	-	-16	А		
Pulse Diode Forward Current	I <sub>SM</sub>		=	-	-60			
Body Diode Voltage	$V_{SD}$	I <sub>S</sub> = -10 A, V <sub>GS</sub> = 0 V	=	-0.75	-1.2	V		
Body Diode Reverse Recovery Time	t <sub>rr</sub>		-	12	25	ns		
Body Diode Reverse Recovery Charge	Q <sub>rr</sub>	I <sub>F</sub> = -10 A, dl/dt = 100 A/μs, T <sub>J</sub> = 25 °C	-	4	10	nC		
Reverse Recovery Fall Time	ta	$I_F = -10 \text{ A}$ , $I_{II}/I_{I} = 100 \text{ A/}\mu\text{s}$ , $I_{I} = 25 ^{-1}\text{C}$	-	7.5	-	ns		
Reverse Recovery Rise Time	t <sub>b</sub>		-	4.5	-			

#### Notes

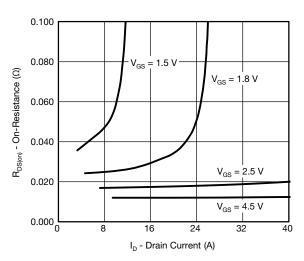
- a. Pulse test; pulse width  $\leq$  300 µs, duty cycle  $\leq$  2 %.
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

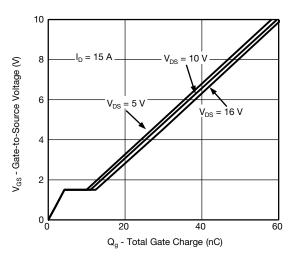




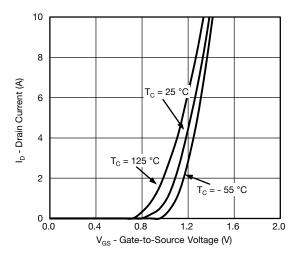
#### **Output Characteristics**



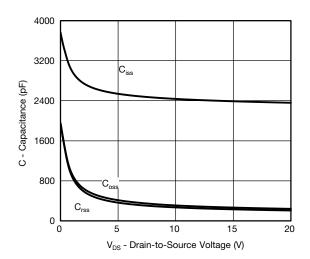
On-Resistance vs. Drain Current and Gate Voltage



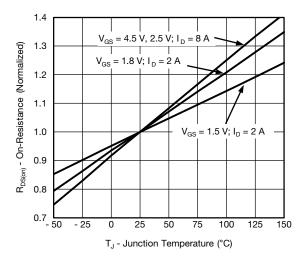
**Gate Charge** 



**Transfer Characteristics** 

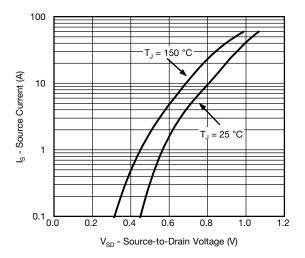


Capacitance

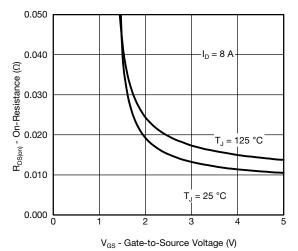


On-Resistance vs. Junction Temperature

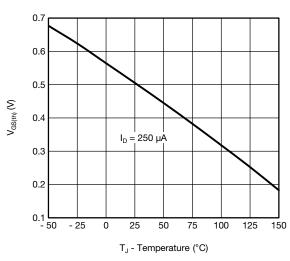




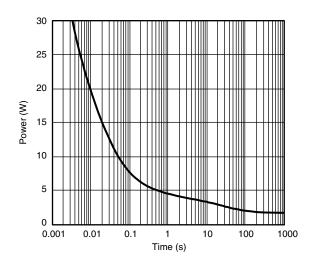
#### Source-Drain Diode Forward Voltage



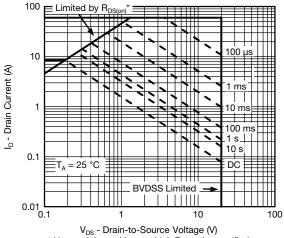
On-Resistance vs. Gate-to-Source Voltage



**Threshold Voltage** 



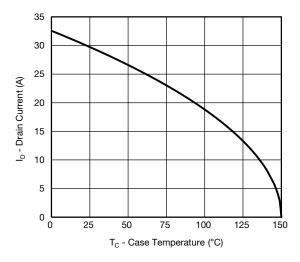
Single Pulse Power, Junction-to-Ambient

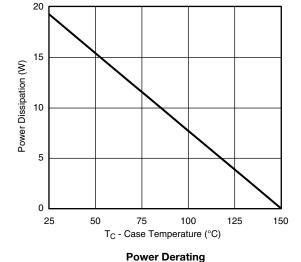


\*  $V_{GS}$  > minimum  $V_{GS}$  at which  $R_{DS(on)}$  is specified

Safe Operating Area, Junction-to-Ambient



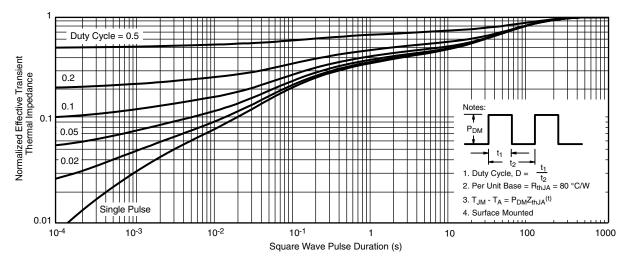




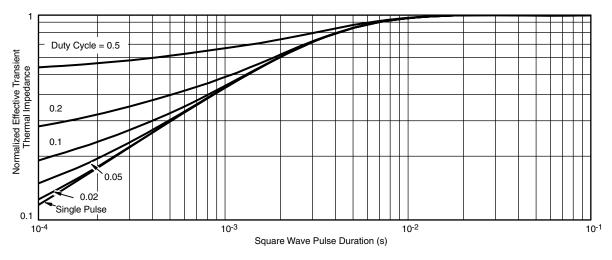
**Current Derating\*** 

<sup>\*</sup> The power dissipation  $P_D$  is based on  $T_{J \text{ (max.)}} = 150 \,^{\circ}\text{C}$ , using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit.





Normalized Thermal Transient Impedance, Junction-to-Ambient

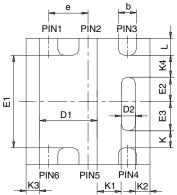


Normalized Thermal Transient Impedance, Junction-to-Case

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see <a href="https://www.vishay.com/ppg?62777">www.vishay.com/ppg?62777</a>.

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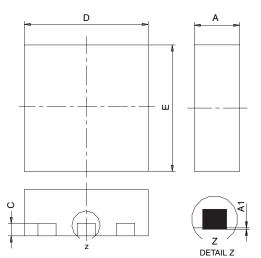
## PowerPAK® SC70-6L





BACKSIDE VIEW OF SINGLE

BACKSIDE VIEW OF DUAL



- All dimensions are in millimeters
  Package outline exclusive of mold flash and metal burr
  Package outline inclusive of plating

	SINGLE PAD						DUAL PAD						
DIM	M	ILLIMETER	RS	INCHES			MILLIMETERS			INCHES			
	Min	Nom	Max	Min	Nom	Max	Min	Nom	Max	Min	Nom	Max	
Α	0.675	0.75	0.80	0.027	0.030	0.032	0.675	0.75	0.80	0.027	0.030	0.032	
A1	0	-	0.05	0	-	0.002	0	-	0.05	0	-	0.002	
b	0.23	0.30	0.38	0.009	0.012	0.015	0.23	0.30	0.38	0.009	0.012	0.015	
С	0.15	0.20	0.25	0.006	0.008	0.010	0.15	0.20	0.25	0.006	0.008	0.010	
D	1.98	2.05	2.15	0.078	0.081	0.085	1.98	2.05	2.15	0.078	0.081	0.085	
D1	0.85	0.95	1.05	0.033	0.037	0.041	0.513	0.613	0.713	0.020	0.024	0.028	
D2	0.135	0.235	0.335	0.005	0.009	0.013							
E	1.98	2.05	2.15	0.078	0.081	0.085	1.98	2.05	2.15	0.078	0.081	0.085	
E1	1.40	1.50	1.60	0.055	0.059	0.063	0.85	0.95	1.05	0.033	0.037	0.041	
E2	0.345	0.395	0.445	0.014	0.016	0.018							
E3	0.425	0.475	0.525	0.017	0.019	0.021							
е		0.65 BSC			0.026 BSC			0.65 BSC			0.026 BSC		
K		0.275 TYP	1		0.011 TYP	1	0.275 TYP		0.011 TYP				
K1		0.400 TYP	1	0.016 TYP			0.320 TYP		0.013 TYP				
K2		0.240 TYP 0.009 TYP			0.252 TYP			0.010 TYP					
К3		0.225 TYP	1	0.009 TYP									
K4		0.355 TYP		0.014 TYP									
L	0.175	0.275	0.375	0.007	0.011	0.015	0.175	0.275	0.375	0.007	0.011	0.015	
Т							0.05	0.10	0.15	0.002	0.004	0.006	
FCN: C-07431 – Rev. C. 06-Aug-07													

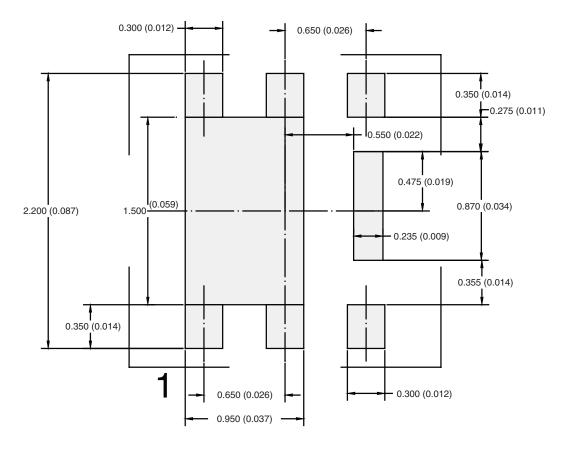
DWG: 5934

Document Number: 73001 06-Aug-07

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## RECOMMENDED PAD LAYOUT FOR PowerPAK® SC70-6L Single



Dimensions in mm/(Inches)

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ATTLICATION NOT



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